

#11/Arndt B
PATENT
J. F. Foch
OFFICE
3/4/03



Applicant: Yuliya Akulova, *et al.*

Serial No.: 09/540,471

Filed: March 31, 2000

Title: Dopant Diffusion Barrier Layer For Use In III-V Structures

Grp./A.U.: 2828

Examiner: T. Nguyen

Honorable Commissioner of Patents
Washington, D.C. 20231

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(Signature of the person signing the certificate)

Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed January 28, 2003, please amend the above-identified application as follows:

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IN THE CLAIMS:

(1) Kindly rewrite Claim 1 as follows:

1. (Twice Amended) An optoelectronics device, comprising:

a doped layer; and

a dopant barrier located between said doped layer and a layer, wherein said dopant barrier

includes at least two layers and does not form a pn junction with said doped layer.